

CMOS Digital Integrated Circuits Silicon Monolithic

# TC74ACT00F

#### 1. Functional Description

· Quad 2-Input NAND Gate

#### 2. General

The TC74ACT00F is an advanced high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate and double-layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

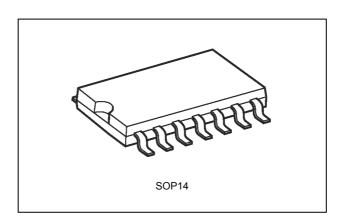
#### 3. Features

- (1) High speed:  $t_{pd} = 4.0 \text{ ns (typ.)}$  at  $V_{CC} = 5.0 \text{ V}$
- (2) Low power dissipation:  $I_{CC} = 4.0 \mu A \text{ (max)}$  at  $T_a = 25 \text{ °C}$
- (3) Compatible with TTL outputs:  $V_{IL} = 0.8 \text{ V (max)}$

$$V_{IH} = 2.0 \text{ V (min)}$$

- (4) Output current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 4.5 \text{ V})$
- (5) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (6) Pin and function compatible with 74F00

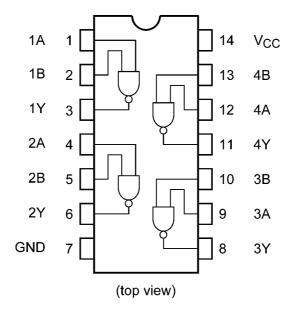
#### 4. Packaging



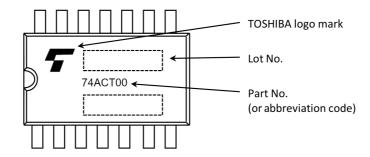
Start of commercial production



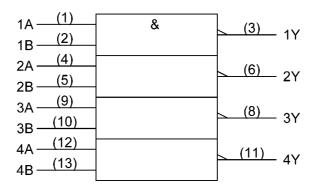
## 5. Pin Assignment



# 6. Marking



# 7. IEC Logic Symbol





#### 8. Truth Table

Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

## 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	l <sub>ok</sub>	±50	mA
Output current	I <sub>OUT</sub>	±50	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>	±100	mA
Power dissipation	$P_D$	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## 10. Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall times	dt/dv	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.



#### 11. Electrical Characteristics

## 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	$V_{IH}$	_		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	$V_{IL}$	_		4.5 to 5.5	_	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50  \mu\text{A}$		4.4	4.5	_	V
			I <sub>OH</sub> = -24 mA	4.5	3.94	_	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.0	0.1	V
			I <sub>OL</sub> = 24 mA	4.5	_	_	0.36	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	μΑ
Quiescent supply	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	μΑ
current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND	Per input: V <sub>IN</sub> = 3.4 V		_	_	1.35	mA

## 11.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		Note	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	$V_{IH}$	_			4.5 to 5.5	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_			4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA		4.5	4.4	_	V
			I <sub>OH</sub> = -24 mA		4.5	3.80	_	
			I <sub>OH</sub> = -75 mA	(Note 1)	5.5	3.85	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA		4.5	_	0.1	V
			I <sub>OL</sub> = 24 mA		4.5	_	0.44	
			I <sub>OL</sub> = 75 mA	(Note 1)	5.5	_	1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	±1.0	μΑ
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND			5.5	_	40.0	μΑ
	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND	•		5.5		1.5	mA

Note 1: This spec indicates the capability of driving 50  $\Omega$  transmission lines. One output should be tested within a 10 ms maximum duration.

# 11.3. AC Characteristics (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$C_L = 50pF$ $R_L = 500\Omega$	5.0±0.5	_	4.7	7.9	ns
Input capacitance	C <sub>IN</sub>		_		_	5	10	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	_		_	23	_	pF

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per gate)

# 11.4. AC Characteristics

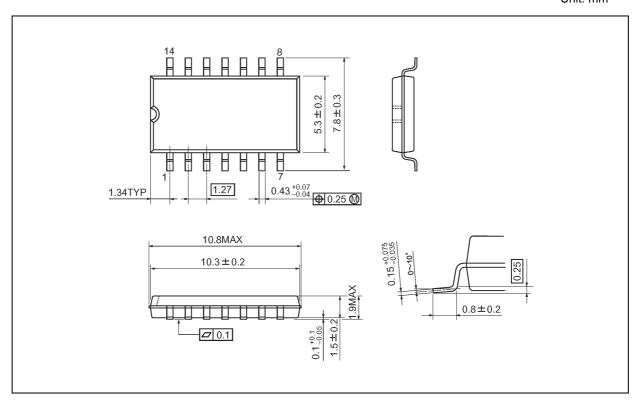
(Unless otherwise specified,  $T_a = -40$  to 85 °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$C_L = 50pF$ $R_L = 500\Omega$	$5.0 \pm 0.5$	1.0	9.5	ns
Input capacitance	C <sub>IN</sub>			_	10	pF



## **Package Dimensions**

Unit: mm



Weight: 0.18 g (typ.)

	Package Name(s)
Nickname: SOP14	



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